



# PHOTOCOUPLER PS2705-1

## HIGH ISOLATION VOLTAGE AC INPUT RESPONSE TYPE SOP MULTI PHOTOCOUPLER

—NEPOC Series—

### DESCRIPTION

The PS2705-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor.

This package is SOP (Small Outline Package) type and has shield effect to cut off ambient light.

It is designed for high density mounting applications.

### FEATURES

- AC input response
- High isolation voltage ( $BV = 3\,750\text{ V r.m.s.}$ )
- High current transfer ratio ( $CTR = 100\% \text{ TYP.}$ )
- SOP (Small Outline Package) type
- High-speed switching ( $t_r = 3\,\mu\text{s TYP.}$ ,  $t_f = 5\,\mu\text{s TYP.}$ )
- Ordering number of taping product : PS2705-1-F3, F4
- UL approved: File No. E72422 (S)
- VDE0884 approved (Option)

### APPLICATIONS

- Hybrid IC
- Telephone/FAX
- FA/OA equipment
- Programmable logic controllers
- Power supply

### ORDERING INFORMATION (Solder Contains Lead)

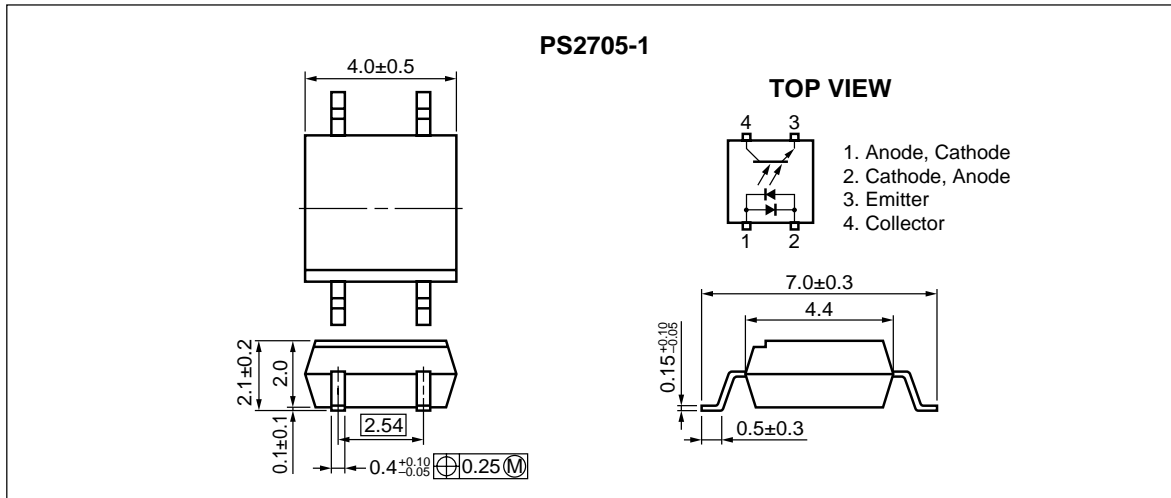
Part Number	Package	Safety Standard Approval
PS2705-1	4-pin SOP	Standard products • UL approved
PS2705-1-V	4-pin SOP	VDE0884 approved products (Option)

### ORDERING INFORMATION (Pb-Free)

Part Number	Package	Safety Standard Approval
PS2705-1-A	4-pin SOP	Standard products • UL approved
PS2705-1-V-A	4-pin SOP	VDE0884 approved products (Option)

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

★ **PACKAGE DIMENSIONS (in millimeters)**



**ABSOLUTE MAXIMUM RATINGS ( $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)**

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	$I_F$	$\pm 50$	mA
	Power Dissipation Derating	$\Delta P_D/^{\circ}\text{C}$	0.8	mW/ $^{\circ}\text{C}$
	Power Dissipation	$P_D$	80	mW
	Peak Forward Current <sup>*1</sup>	$I_{FP}$	$\pm 1$	A
Transistor	Collector to Emitter Voltage	$V_{CEO}$	40	V
	Emitter to Collector Voltage	$V_{ECO}$	6	V
	Collector Current	$I_C$	80	mA
	Power Dissipation Derating	$\Delta P_C/^{\circ}\text{C}$	1.5	mW/ $^{\circ}\text{C}$
	Power Dissipation	$P_C$	150	mW
Isolation Voltage <sup>*2</sup>		$BV$	3 750	Vr.m.s.
Operating Ambient Temperature		$T_A$	-55 to +100	$^{\circ}\text{C}$
Storage Temperature		$T_{stg}$	-55 to +150	$^{\circ}\text{C}$

\*1  $PW = 100\text{ }\mu\text{s}$ , Duty Cycle = 1 %

\*2 AC voltage for 1 minute at  $T_A = 25\text{ }^{\circ}\text{C}$ , RH = 60 % between input and output

ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ )

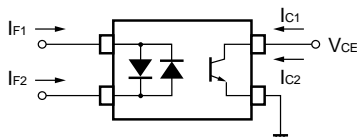
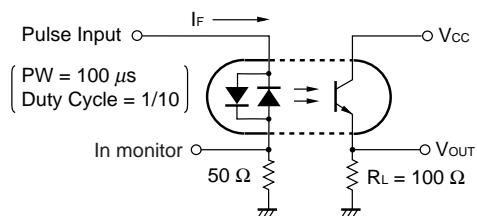
Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	$V_F$	$I_F = \pm 5\text{ mA}$		1.1	1.4	V
	Terminal Capacitance	$C_i$	$V = 0\text{ V}, f = 1\text{ MHz}$		60		pF
Transistor	Collector to Emitter Dark Current	$I_{CEO}$	$I_F = 0\text{ mA}, V_{CE} = 40\text{ V}$			100	nA
Coupled	Current Transfer Ratio $(I_C/I_F)^{-1}$	CTR	$I_F = \pm 5\text{ mA}, V_{CE} = 5\text{ V}$	50	100	300	%
	CTR Ratio <sup>*2</sup>	$CTR_1/CTR_2$	$I_F = \pm 5\text{ mA}, V_{CE} = 5\text{ V}$	0.3	1.0	3.0	
	Collector Saturation Voltage	$V_{CE(sat)}$	$I_F = \pm 10\text{ mA}, I_C = 2\text{ mA}$			0.3	V
	Isolation Resistance	$R_{I-O}$	$V_{I-O} = 1\text{ kV}_{DC}$	$10^{11}$			$\Omega$
	Isolation Capacitance	$C_{I-O}$	$V = 0\text{ V}, f = 1\text{ MHz}$		0.4		pF
	Rise Time <sup>*3</sup>	$t_r$	$V_{CC} = 5\text{ V}, I_C = 2\text{ mA}, R_L = 100\ \Omega$		3		$\mu\text{s}$
	Fall Time <sup>*3</sup>	$t_f$			5		

**\*1 CTR rank**

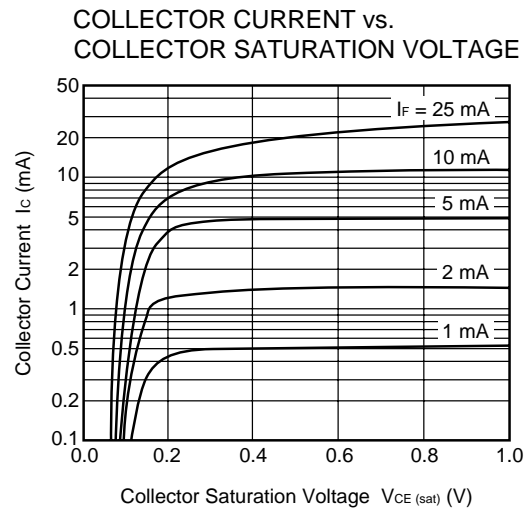
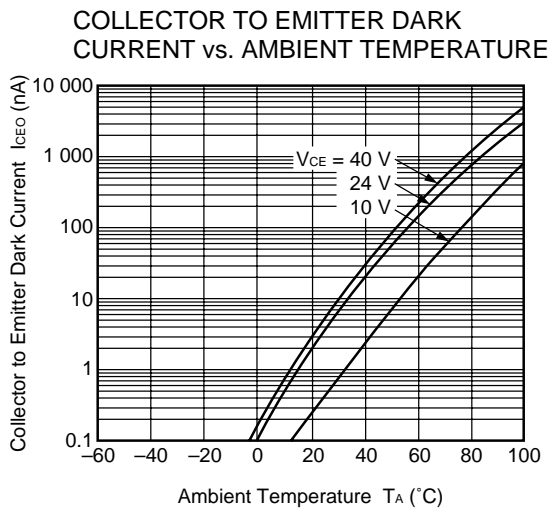
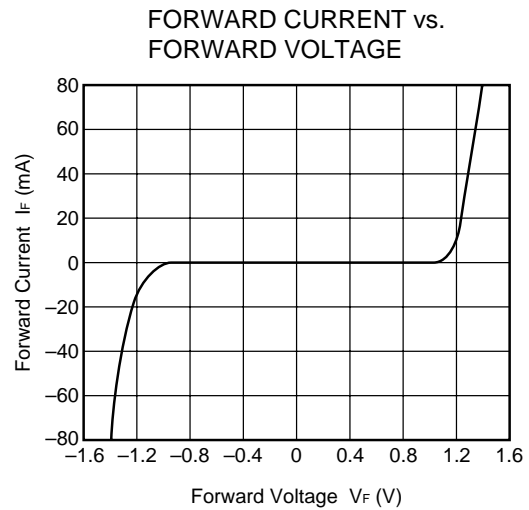
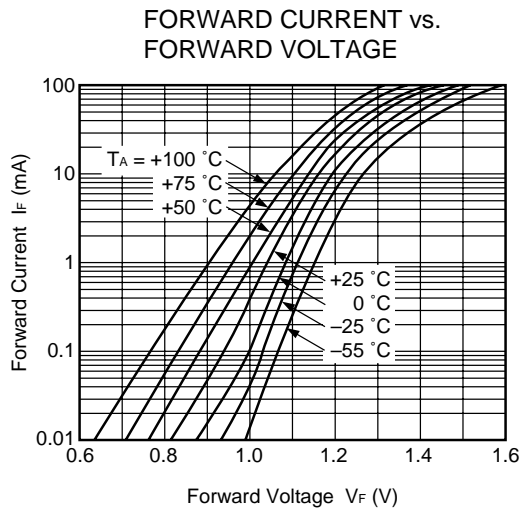
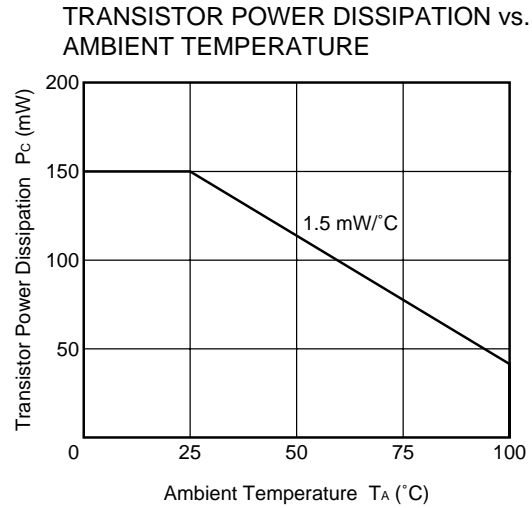
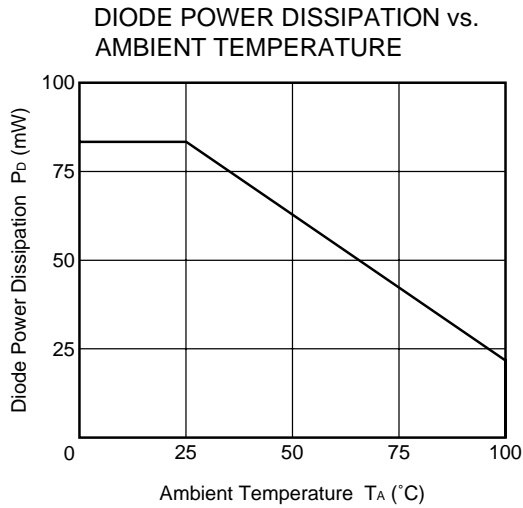
M: 50 to 150 (%)

L: 100 to 300 (%)

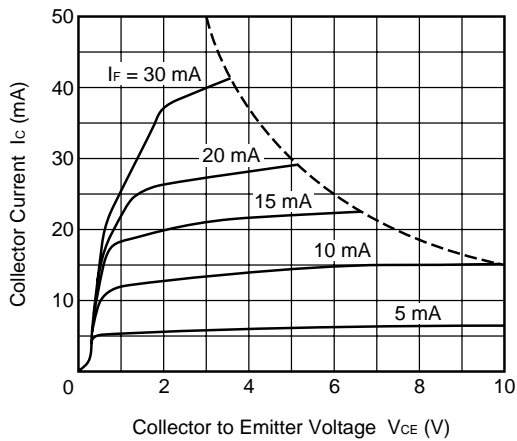
N: 50 to 300 (%)

**\*2  $CTR_1 = I_{C1}/I_{F1}$ ,  $CTR_2 = I_{C2}/I_{F2}$** **\*3 Test circuit for switching time**

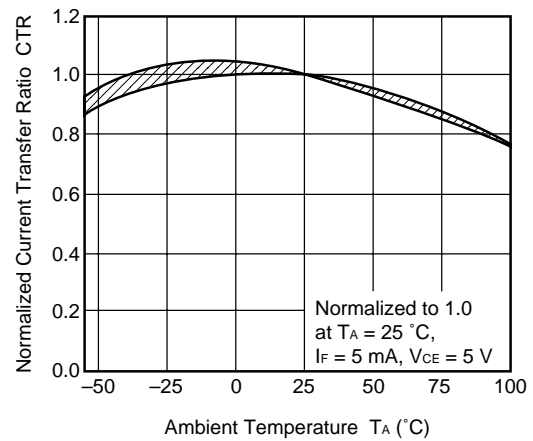
★ TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ , unless otherwise specified)



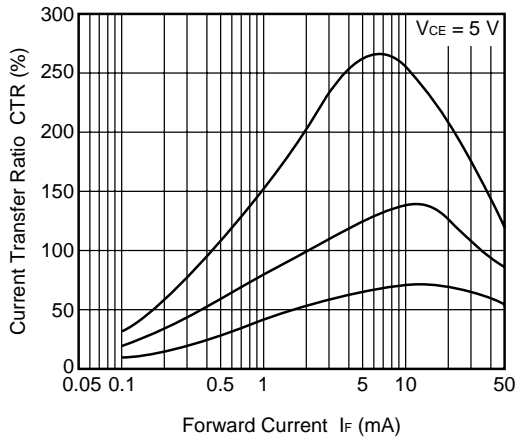
COLLECTOR CURRENT vs.  
COLLECTOR TO EMITTER VOLTAGE



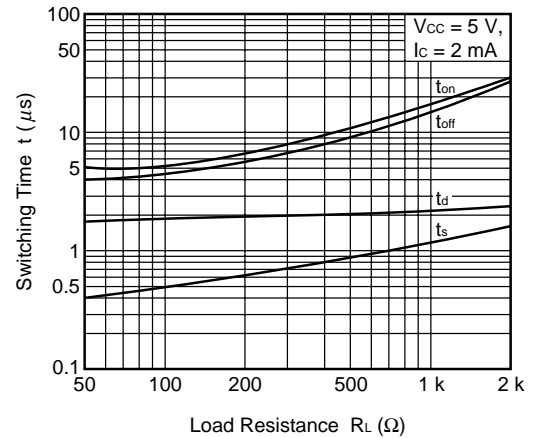
NORMALIZED CURRENT TRANSFER  
RATIO vs. AMBIENT TEMPERATURE



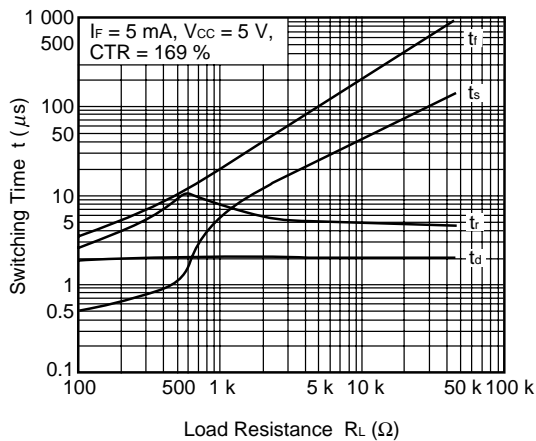
CURRENT TRANSFER RATIO vs.  
FORWARD CURRENT



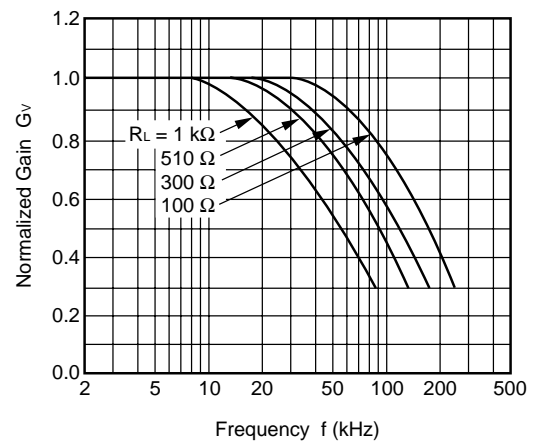
SWITCHING TIME vs.  
LOAD RESISTANCE

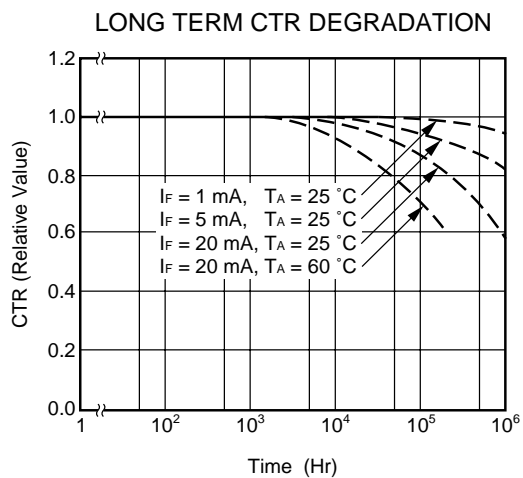


SWITCHING TIME vs.  
LOAD RESISTANCE



FREQUENCY RESPONSE

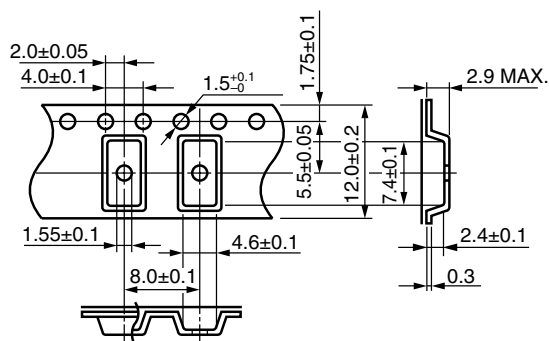




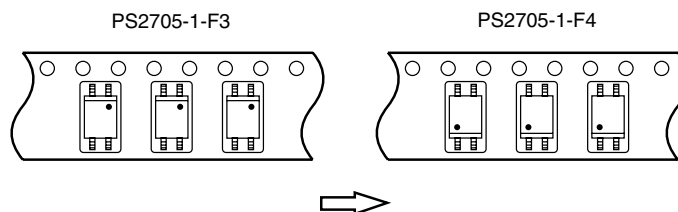
**Remark** The graphs indicate nominal characteristics.

## ★ TAPING SPECIFICATIONS (in millimeters)

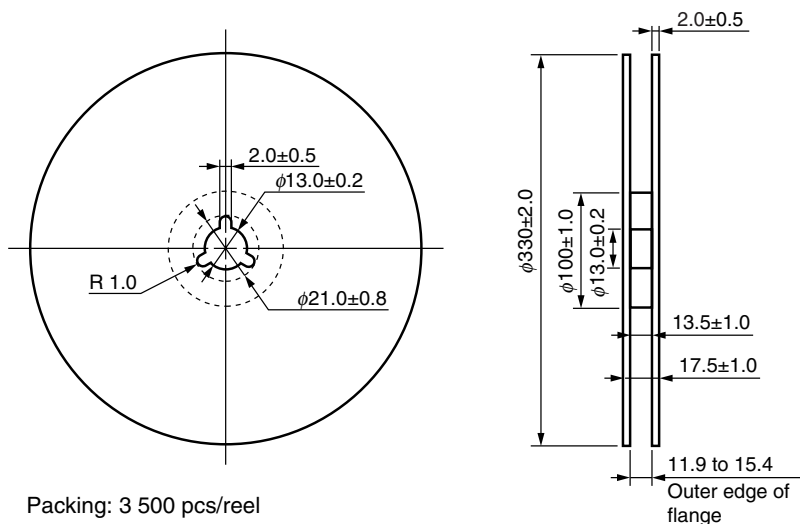
Outline and Dimensions (Tape)



Tape Direction



Outline and Dimensions (Reel)



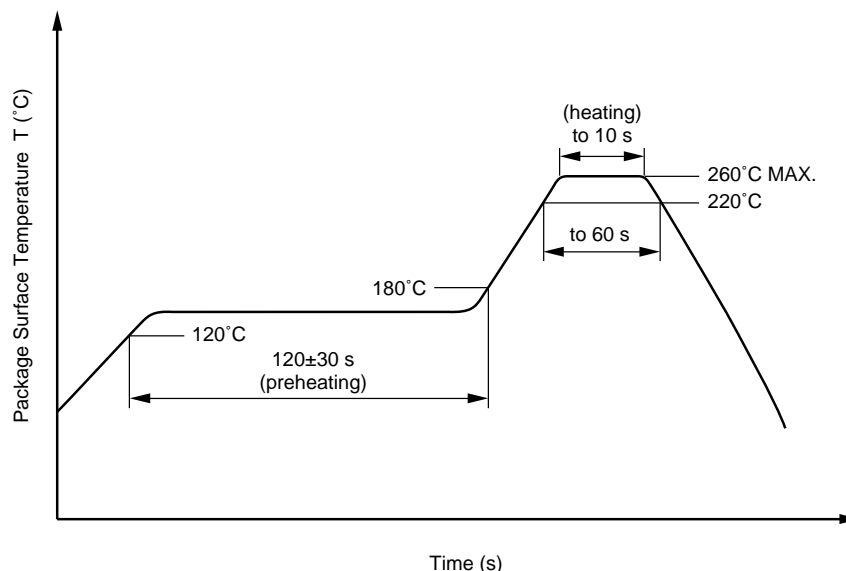
## ★ NOTES ON HANDLING

## 1. Recommended soldering conditions

## (1) Infrared reflow soldering

- Peak reflow temperature 260°C or below (package surface temperature)
- Time of peak reflow temperature 10 seconds or less
- Time of temperature higher than 220°C 60 seconds or less
- Time to preheat temperature from 120 to 180°C 120±30 s
- Number of reflows Three
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



## (2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

## (3) Cautions

- Fluxes Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

## 2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

**★ USAGE CAUTIONS**

1. Protect against static electricity when handling.
2. Avoid storage at a high temperature and high humidity.

## SPECIFICATION OF VDE MARKS LICENSE DOCUMENT (VDE0884)

Parameter	Symbol	Spec	Unit
Application classification (DIN VDE 0109) for rated line voltages $\leq 300$ Vr.m.s. for rated line voltages $\leq 600$ Vr.m.s.		IV III	
Climatic test class (DIN IEC 68 Teil 1/09.80)		55/100/21	
Dielectric strength Maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.2 \times U_{IORM}$ , $P_d < 5$ pC	$U_{IORM}$ $U_{pr}$	710 850	$V_{peak}$ $V_{peak}$
★ Test voltage (partial discharge test, procedure b for all devices test) $U_{pr} = 1.6 \times U_{IORM}$ , $P_d < 5$ pC	$U_{pr}$	1 140	$V_{peak}$
Highest permissible overvoltage	$U_{TR}$	6 000	$V_{peak}$
Degree of pollution (DIN VDE 0109)		2	
Clearance distance		> 5	mm
Creepage distance		> 5	mm
Comparative tracking index (DIN IEC 112/VDE 0303 part 1)	CTI	175	
Material group (DIN VDE 0109)		III a	
Storage temperature range	$T_{stg}$	-55 to +150	°C
Operating temperature range	$T_A$	-55 to +100	°C
Isolation resistance, minimum value $V_{IO} = 500$ V dc at $T_A = 25$ °C $V_{IO} = 500$ V dc at $T_A$ MAX. at least 100 °C	Ris MIN. Ris MIN.	$10^{12}$ $10^{11}$	$\Omega$ $\Omega$
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current $I_F$ , $P_{si} = 0$ ) Power (output or total power dissipation) Isolation resistance $V_{IO} = 500$ V dc at $T_A = 175$ °C ( $T_{si}$ )	$T_{si}$ $I_{si}$ $P_{si}$ Ris MIN.	150 200 300 $10^9$	°C mA mW $\Omega$

Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (\*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices	
		-A	-AZ
Lead (Pb)	< 1000 PPM	Not Detected	(*)
Mercury	< 1000 PPM	Not Detected	
Cadmium	< 100 PPM	Not Detected	
Hexavalent Chromium	< 1000 PPM	Not Detected	
PBB	< 1000 PPM	Not Detected	
PBDE	< 1000 PPM	Not Detected	

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

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